NSN 5961-00-836-0302

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-836-0302 **Inclosure Material:** Metal **Overall Length:** 0.220 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.210 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 10.5 reverse breakdown voltage, dc **Current Rating Per Characteristic:** 100.00 milliamperes forward current, average absolute **Power Rating Per Characteristic:** 150.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Precious Material And Location:** Lead surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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